2SK1808

Silicon N-Channel MOS FET

HITACHI

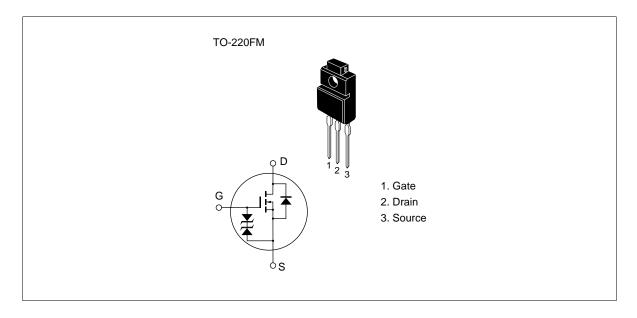
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- · No secondary breakdown
- Suitable for switchingregulator, DC-DC converter

Outline





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Absolute Maximum Ratings $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	900	V
Gate to source voltage	$V_{\rm GSS}$	±30	V
Drain current	I _D	4	A
Drain peak current	I _{D(pulse)} *1	10	A
Body to drain diode reverse drain current	I _{DR}	4	A
Channel dissipation	Pch*2	35	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes 1. PW 10 µs, duty cycle 1 %

2. Value at Tc = 25 °C

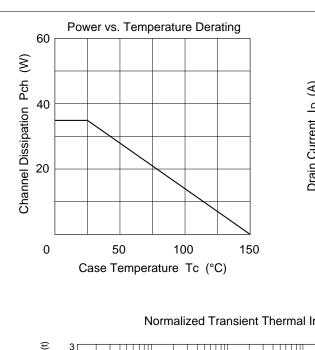
Electrical Characteristics (Ta = 25°C)

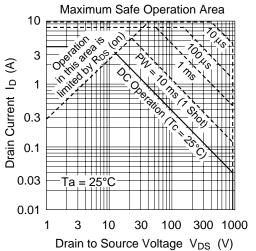
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	900	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±30	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μA	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	250	μΑ	$V_{DS} = 720 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{\rm GS(off)}$	2.0	_	3.0	V	$I_{D} = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	_	3.0	4.0		$I_D = 2 A$ $V_{GS} = 10 V^{*1}$
Forward transfer admittance	y _{fs}	1.7	2.7	_	S	I _D = 2 A V _{DS} = 10 V* ¹
Input capacitance	Ciss	_	740	_	pF	V _{DS} = 10 V
Output capacitance	Coss	_	305	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	150	_	pF	f = 1 MHz
Turn-on delay time	$\mathbf{t}_{\text{d(on)}}$	_	15	_	ns	$I_D = 2 A$
Rise time	t _r	_	60	_	ns	V _{GS} = 10 V
Turn-off delay time	t _{d(off)}	_	100	_	ns	$R_{L} = 15$
Fall time	t _f	_	80	_	ns	
Body to drain diode forward voltage	V_{DF}	_	0.9	_	V	$I_F = 4 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t _{rr}	_	800	_	ns	$I_F = 4 \text{ A}, V_{GS} = 0,$ $di_F / dt = 100 \text{ A} / \mu \text{s}$

Note 1. Pulse Test

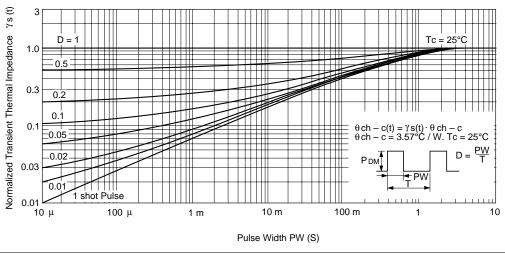
See characteristic curves of 2SK1340

2SK1808





Normalized Transient Thermal Impedance vs. Pulse Width



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IITACHI

Hitachi, Ltd.

Semiconductor & IC Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

For further information write to:

Hitachi America, Ltd. Semiconductor & IC Div. 2000 Sierra Point Parkway Brisbane, CA. 94005-1835 USA

Tel: 415-589-8300 Fax: 415-583-4207 Hitachi Europe GmbH Electronic Components Group Continental Europe Dornacher Straße 3 D-85622 Feldkirchen München

Tel: 089-9 91 80-0 Fax: 089-9 29 30 00 Hitachi Europe Ltd. Electronic Components Div. Northern Europe Headquarters Whitebrook Park Lower Cookham Road Maidenhead Berkshire SI 6 8YA United Kingdom Tel: 0628-585000

Fax: 0628-778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 0104 Tel: 535-2100 Fax: 535-1533

Hitachi Asia (Hong Kong) Ltd. Unit 706, North Tower, World Finance Centre, Harbour City, Canton Road Tsim Sha Tsui. Kowloon Hong Kong

Tel: 27359218 Fax: 27306071